

# APPLICATION DATA SHEET

Electronic Version 0.0.11

Stylesheet Version: 1.0

Attorney Docket Number: EMEP0021USA

Publication Filing Type: new-utility

Application Type: utility

Title of Invention: STRUCTURE OF AN EMBEDDED CHANNEL WRITE/ERASE FLASH  
MEMORY CELL AND FABRICATING METHOD THEREOF

Customer Number Attorney: 027765



Customer Number Correspondence Address: 027765



## Continuity Data:

This application is a division of 09/865,432 2001-05-29 pending

## Foreign Priority:

09/865,432 US 2001-05-29 Priority Claimed

## INVENTOR(s):

Primary Citizenship: R.O.C.

Given Name: Ching-Hsiang

Family Name: Hsu

Residence City: Hsin-Chu City

Residence Country: TW

Address: No.100-28, Chien-Chung Rd., Hsin-Chu City, Taiwan,  
R.O.C.

Hsin-Chu City , TW

Primary Citizenship: R.O.C.

Given Name: Ching-Sung

Family Name: Yang

Residence City: Chang-Hua Hsien

Residence Country: TW  
Address: No.5, Lane 425, Sec.2, Ta-Hsi Rd., Hsi-Hu Town,  
Chang-Hua Hsien, Taiwan, R.O.C.  
Chang-Hua Hsien , TW